NSN 5961-00-199-5030



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-199-5030 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between -2.00 amperes source cutoff current and -4.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:**

81349-mil-s-19500/441 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig: